



PVSEC-11 (1999) / Sapporo, Japan

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	*T. Wada, **Y. Hashimoto, **S. Nishiwaki, **T. Sato, **S. Hayashi, **T. Negami and ***H. Miyake *Ryukoku Univ., Japan **Matsushita Electric Industrial Co., Ltd., Japan *** Mie Univ., Japan
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E. F. Lisbona and K. P. Bogus
European Space Research and Technology Centre, The Netherlands

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(invited) S. Matsuda, K. Shinozaki, T. Aburaya, K. Aoyama and O. Anzawa
National Space Development Agency of Japan, Japan

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*T. Hisamatsu, **H. Okamoto, ***N. Shiono, ****T. Aburaya and ****S. Matsuda
*Sharp Corp., Japan **Osaka Univ., Japan ***Reliability Center for Electronic Components of Japan, Japan ****National Space Development Agency of Japan, Japan

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*J. Haapamaa, *M. Pessa and **G. La Roche
*Tampere Univ. of Technology, Finland **Domier Satellite Systems, Germany

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Universite P. et M. Curie, France

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*A. Khan, *M. Yamaguchi, **T. Aburaya and **S. Matsuda
*Toyota Technological Institute, Japan **National Space Development Agency of Japan

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*R. J. Waiters, *G. P. Summers, **M. J. Romero, **D. Araujo, **R. Garcia and ***S. R. Messenger
*U.S. Naval Research Laboratory, USA ** Universidad de Cadiz, Spain ***SFA, Inc., USA

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(invited) N. H. Karam
HUGHES, Spectrolab, USA

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P. K. Chiang, C. L. Chu, Y. C. M. Yeh, P. Iies and F. Ho
TECSTARIASD, USA

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*S. J. Taylor, *C. M. Hardingham, *C. R. Huggins, *A. Kelt, *S. Wood, *J. Simpson, *J. Burrage, *A. Hayward, *R. Ginige, *T. Cross, **C. Clark and **V. Van del Zel
*EEV Ltd., Solar Power Systems, UK **Univ., of Surrey, UK

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*Y. Tonomura, *M. Hagino, *H. Washio, *M. Kaneiwa, *T. Saga, **O. Anzawa, **K. Aoyama, **K. Shinozaki, and **S. Matsuda
*Sharp Corp., Japan **National Space Development Agency of Japan, Japan

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(invited) I. Shimizu
Tokyo Institute of Technology, Japan

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	Werkstoffwissenschaften, Germany ****Siemens AG, Germany *****Angewandte Solarenergie, Germany *****Universitat Erlangen-Nürnberg, Germany
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*New Energy and Industrial Technology Development Organization, Japan **Showa Shell Sekiyu K. K., Japan

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